

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	884	composite adj3 gate	USPAT; US-PG PUB
2	BRS	L2	36	("sio" or (silicon adj2 oxide)) near20 1	USPAT; US-PG PUB
3	BRS	L3	14	("sin" or (silicon adj2 nitride)) near20 2	USPAT; US-PG PUB
4	BRS	L4	63	("sio" or (silicon adj2 oxide)) same 1	USPAT; US-PG PUB
5	BRS	L5	30	("sin" or (silicon adj2 nitride)) same 4	USPAT; US-PG PUB
6	BRS	L6	16	5 not 3	USPAT; US-PG PUB
7	BRS	L7	1	5 and (tft)	USPAT; US-PG PUB
8	BRS	L8	8238	substrate near10 (buffer adj2 (layer or film))	USPAT; US-PG PUB
9	BRS	L9	468	8 and (tft)	USPAT; US-PG PUB
10	BRS	L10	6069	substrate near4 (buffer adj2 (layer or film))	USPAT; US-PG PUB
11	BRS	L11	658	("on" or "over" near3 substrate) near10 (buffer adj2 (layer or film))	USPAT; US-PG PUB

EAST-AMERICA CO.